INTEGRATED CIRCUITS

DATA SHEET



74LVC27Triple 3-input NOR gate

Product specification Supersedes data of 1998 Apr 06 IC24 Data Handbook





Triple 3-input NOR gate

74LVC27

FEATURES

- Wide supply voltage: 1.2 to 3.6 V
- In accordance with JEDEC standard no. 8-1A.
- Inputs accept voltages up to 5.5 V
- CMOS low power consumption
- Direct interface with TTL levels
- Output capability: standard
- I_{CC} category: SSI

DESCRIPTION

The 74LVC27 is a high-performance, low-power, low-voltage Si-gate CMOS device and superior to most advanced CMOS compatible

The 74LVC27 provides the 3-input NOR function.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5 \text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay nA, nB, nC to nY	$C_L = 50 \text{ pF};$ $V_{CC} = 3.3 \text{ V}$	3.4	ns
C _I	Input capacitance	1 1 1	5.0	pF
C _{PD}	Power dissipation capacitance per gate	Notes 1 and 2	26	pF
$P_D = C_{PD} \times V_{CC}^2 \times f_i$ $f_i = \text{input frequency in}$,com.c		

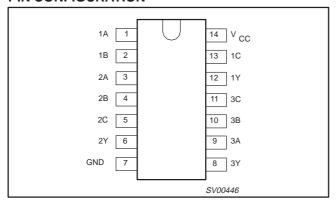
NOTES:

- 1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW) $\begin{array}{l} P_D = C_{PD} \times V_{CC}{}^2 \times f_i + \sum \left(C_L \times V_{CC}{}^2 \times f_o \right) \text{ where:} \\ f_i = \text{input frequency in MHz; } C_L = \text{output load capacity in pF;} \\ f_o = \text{output frequency in MHz; } V_{CC} = \text{supply voltage in } V_i \end{array}$
- $\sum_{i=0}^{\infty} (C_L \times V_{CC}^2 \times f_0) = \text{sum of the outputs.}$ 2. The condition is $V_I = \text{GND to } V_{CC}$.

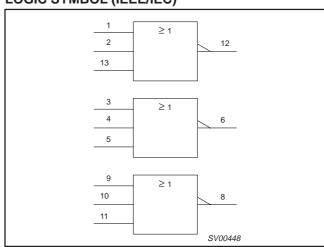
ORDERING INFORMATION

OTTO THE OTTO THE				
PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic SO	-40°C to +85°C	74LVC27 D	74LVC27 D	SOT108-1
14-Pin Plastic SSOP Type II	-40°C to +85°C	74LVC27 DB	74LVC27 DB	SOT337-1
14-Pin Plastic TSSOP Type I	-40°C to +85°C	74LVC27 PW	74LVC27PW DH	SOT402-1

PIN CONFIGURATION



LOGIC SYMBOL (IEEE/IEC)



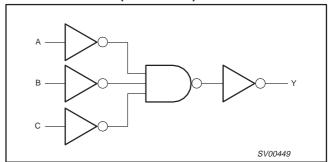
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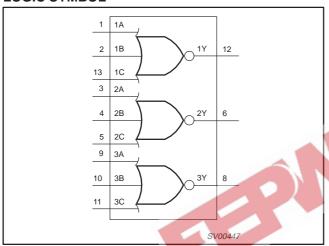
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 3, 9	1A – 3A	Data inputs
2, 4, 10	1B – 3B	Data inputs
13, 5, 11	1C – 3C	Data inputs
7	GND	Ground (0 V)
12, 6, 8	1Y – 3Y	Data outputs
14	V _{CC}	Positive supply voltage

LOGIC DIAGRAM (ONE GATE)



LOGIC SYMBOL



FUNCTION TABLE

	INPUTS							
nA	nВ	nC	nY					
L s	水平	L	Н					
XX	X	Н	L					
X	Н	Х	L					
HO	Х	Х	L					

NOTES:

H = HIGH voltage level L = LOW voltage level X = don't care

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LIM	UNIT	
STWIBOL	TANAMETER	CONDITIONS	MIN	MAX	ONT
V _{CC}	DC supply voltage (for max. speed performance)		2.7	3.6	V
V _{CC}	DC supply voltage (for low-voltage applications)		1.2	3.6	V
V _I	DC input voltage range		0	5.5	V
Vo	DC output voltage range		0	V _{CC}	V
T _{amb}	Operating free-air temperature range		-40	+85	°C
t _r , t _f	Input rise and fall times	$V_{CC} = 1.2 \text{ to } 2.7V$ $V_{CC} = 2.7 \text{ to } 3.6V$	0	20 10	ns/V

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ABSOLUTE MAXIMUM RATINGS¹

In accordance with the Absolute Maximum Rating System (IEC 134)

Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +6.5	V
I _{IK}	DC input diode current	V _I < 0	-50	mA
V _I	DC input voltage	Note 2	-0.5 to +5.5	V
lok	DC output diode current	$V_O > V_{CC}$ or $V_O < 0$	±50	mA
V _O	DC output voltage	Note 2	-0.5 to V _{CC} +0.5	V
Ι _Ο	DC output source or sink current	$V_O = 0$ to V_{CC}	±50	mA
I _{GND} , I _{CC}	DC V _{CC} or GND current		±100	mA
T _{stg}	Storage temperature range		-60 to +150	°C
P _{TOT}	Power dissipation per package – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	500 500	mW

NOTES

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions voltages are referenced to GND (ground = 0V)

			ι			
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = -	40°C to ⋅	+85°C	UNIT
			MIN	TYP ¹	MAX	1
V	HIGH level Input voltage	V _{CC} = 1.2V	V _{CC}			V
V_{IH}	HIGH level input voltage	V _{CC} = 2.7 to 3.6V	2.0]
V	LOW love land voltage	V _{CC} = 1.2V			GND	V
V_{IL}	LOW level Input voltage	V _{CC} = 2.7 to 3.6V			0.8	ľ
		$V_{CC} = 2.7V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -12$ mA	V _{CC} - 0.5			
V	HICH lovel output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -100 \mu A$	V _{CC} -0.2	V _{CC}		
V _{OH}	HIGH level output voltage	$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -12mA$	V _{CC} -0.6			ľ
		$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -24$ mA	V _{CC} - 1.0			
		$V_{CC} = 2.7V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 12mA$			0.40	
V_{OL}	LOW level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		GND	0.20	V
		$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 24mA$			0.55	
l _l	Input leakage current	V _{CC} = 3.6V; V _I = 5.5V or GND		± 0.1	±5	μΑ
I _{CC}	Quiescent supply current	$V_{CC} = 3.6V$; $V_I = V_{CC}$ or GND; $I_O = 0$		0.1	10	μΑ
Δl _{CC}	Additional quiescent supply current per input pin	$V_{CC} = 2.7V \text{ to } 3.6V; V_I = V_{CC} - 0.6V; I_O = 0$		5	500	μА

NOTE

Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the
device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to
absolute-maximum-rated conditions for extended periods may affect device reliability.

^{2.} The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^{1.} All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

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AC CHARACTERISTICS

GND = 0 V; t_f = t_f \leq 2.5 ns; C_L = 50 pF; R_L = 500 Ω ; T_{amb} = $-40^{\circ}C$ to +85 $^{\circ}C$

SYMBOL	PARAMETER	WAVEFORM	Vco	_C = 3.3V ±0	.3V	V _{CC} = 2.7V		UNIT
			MIN	TYP ¹	MAX	MIN	MAX	
t _{PHL} /	Propagation delay nA, nB, nC to nY	Figure 1, 2	-	3.4	5.9	-	7.0	ns

NOTE:

1. These typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

AC WAVEFORMS

 V_M = 1.5 V at $V_{CC}\,\geq\,2.7$ V

 V_{M} = 0.5 • V_{CC} at V_{CC} < 2.7 V V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.

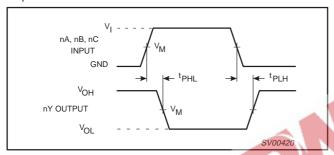


Figure 1. Input (nA, nB, nC) to output (nY) propagation delays.

TEST CIRCUIT

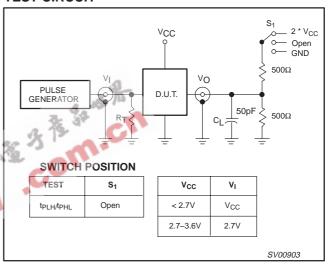


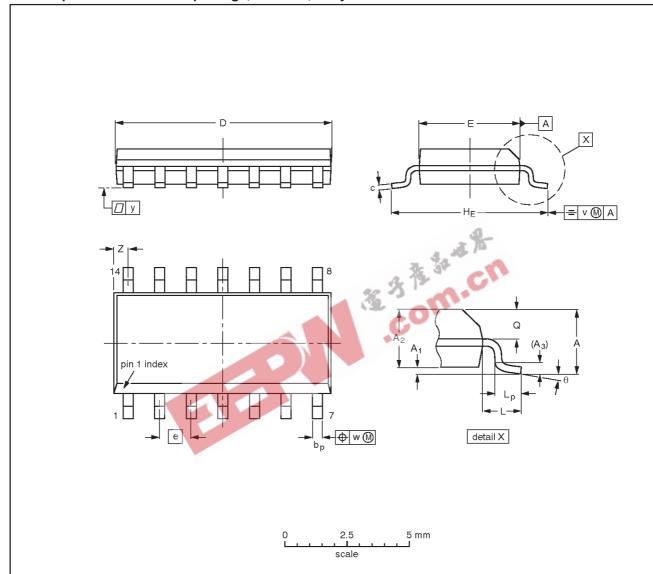
Figure 2. Load circuitry for switching times.

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SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.35 0.34	0.16 0.15	0.050	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

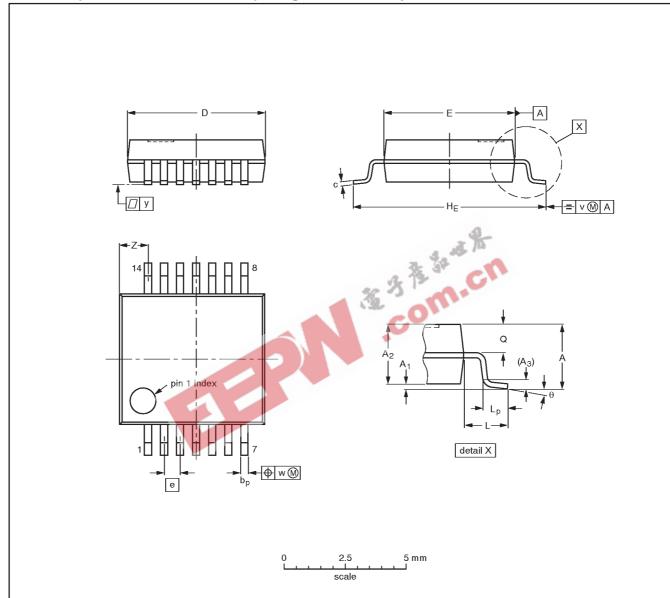
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VERSION	ERSION IEC		EIAJ	PROJECTION	ISSUE DATE
SOT108-1	076E06S	MS-012AB			95-01-23 97-05-22

Triple 3-input NOR gate

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SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



DIMENSIONS (mm are the original dimensions)

						-,												
UNIT	A max.	Α ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

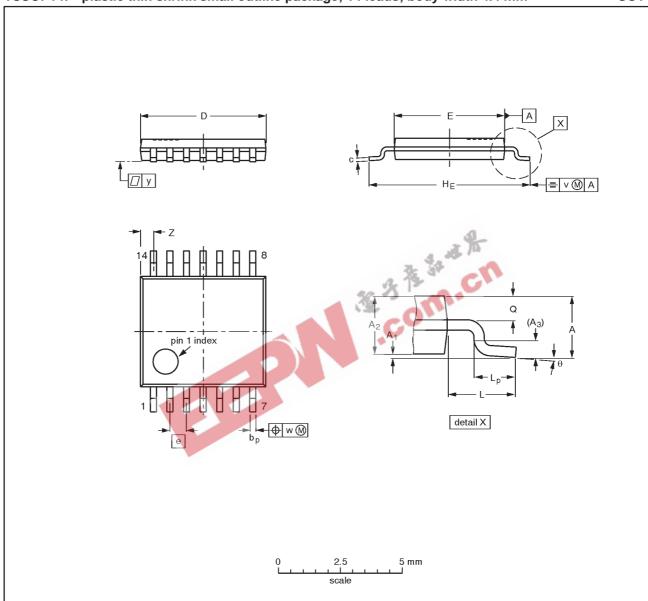
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VERSION	VERSION IEC JEDEC EIAJ			PROJECTION	ISSUE DATE	
SOT337-1		MO-150AB				-95-02-04 96-01-18

Triple 3-input NOR gate

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TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



DIMENSIONS (mm are the original dimensions)

J.1101 E.140	10110 (1	iiiii ai c	and ong	illiai aili	101101011	٠,												
UNIT	A max.	Α1	A ₂	Α3	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT402-1		MO-153			94-07-12 95-04-04	

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NOTES



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Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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^[1] Please consult the most recently issued datasheet before initiating or completing a design.

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